NPO/COG for General-use is class I high frequency capacitor, its capacitance is very stable, almost will not change along with the temperature, voltage and time. Specially be suitable for high frequency circuits.

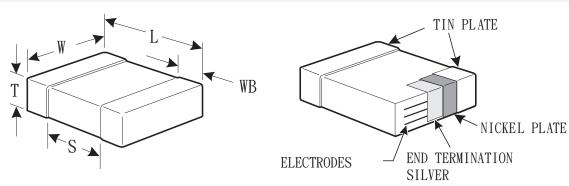
#### **FEATURES**

- Miniature size
- Wide capacitance, TC, voltage and tolerance range
- Industry standard sizes
- Available for wave, reflow or vapor phase solder

#### **HOW TO ORDER**

0805		CG		102		J		500		N		Т
I		1		1		1		1		1		I
Α		В		С		D		E		F	G	
Size Code	Die	lectric	Capac	citance(pF)	To	olerance	Rate	d Voltage	Т	ermination	Pack	aging Style
0402	CG	COG	1R0	1pF	В	±0.10pF	160	16V	S	Silver	No Mark	Bulk
0603	CG	(NPO)	100	10pF	С	±0.25pF	250	250V	N.I	Nickel Barrier	Т	Tape & Reel
0805			101	100pF	D	±0.5pF	500	50V	N	Tin Plating	В	Bulk Package
1206			102	1000pF	F	±1.0%	630	63V				
			103	10000pF	G	±2.0%	101	100V				
					J	±5.0%	201	200V				
					K	±10%	501	500V				
					M	±20%	102	1000V				
							202	2000V				

#### **TERMINATION DIAGRAMS**



NOTE: Other Termination Available Upon Request (Contact Factory)





### SIZE CODE CAPACITANCE and VOLTAGE

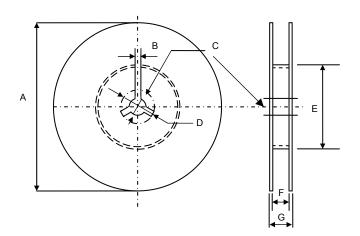
Туре			Dimensio	Voltage	Capacitance(pF)		
Size Code	Metric Expression	L	w	Т	WB		NPO(COG)
	4005			0.50.0.5		10V	0R5~471
0402		4.00.0.05	0.50.005		0.05.0.4	16V	0R5~471
0402	1005	1.00±0.05	0.50±0.05	0.50±0.05	0.25±0.1	25V	1R0~471
						50V	1R0~221
						25V	0R5~102
0603	1608	1.60±0.1	0.80±0.10	0.80±0.1	0.30±0.1	50V	0R5~102
0003	1000	1.00±0.1	0.80±0.10	0.00±0.1	0.30±0.1	100V	0R5~561
						200V	0R5~331
				0.80±0.10		25V	0R5~472
	2012	2.00±0.20	1.25±0.20		0.5±0.25	50V	0R5~472
0805				1.00±0.10		100V	0R5~102
						200V	0R5~821
				1.25±0.20		500V	0R5~471
						25V	0R5~153
	3216	3.20±0.30	1.60±0.20	0.80±0.10 1.00±0.10 1.25±0.20	0.50±0.25	50V	0R5~153
						100V	0R5~152
1206						200V	0R5~102
						500V	0R5~821
						1000V	0R5~471
						2000V	0R5~682
						25V	561~153
						50V	561~153
				1.25±0.30		100V	561~472
1210	3225	3.20±0.30	2.50±0.30		0.75±0.25	200V	101~472
				1.25±0.30		500V	101~222
						1000V	101~102
						2000V	101~561

### **PACKAGING**

### **Structure and Dimension**

Tape & Reel

Α	В	С	D	E	F	G
178±2.00	3.00	13±0.50	21±0.80	50 min	10.0±1.50	12 max
330±2.00	3.00	13±0.50	21±0.80	50 min	10.0±1.50	12 max

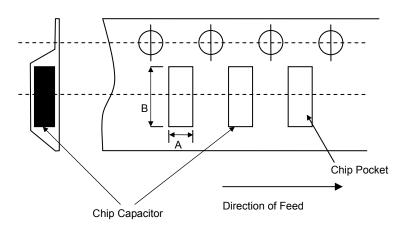






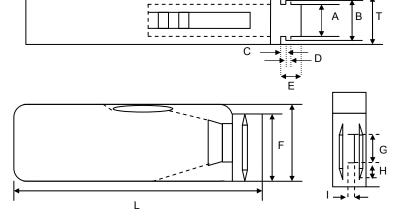
### Paper Tape

. 460. 1460		
Size	Α	В
0402	0.6±0.2	1.1±0.2
0603	1.1±0.2	1.4±0.2
0805	1.45±0.2	2.3±0.2
1206	1.8±0.2	3.4±0.2
Embossed Tape		
Size	Α	В
0402	0.5±0.2	1.2±0.2
0603	0.8±0.2	2.0±0.2
0805	1.65±0.2	2.4±0.2
1206	2.0±0.2	3.6±0.2



#### Cartridge

Cartilage	_					
Symbol	Α	В	D	С	Т	E
Dimension	6.8±0.1	8.8±0.1	12±0.1	15±0.1-0	2±0-0.1	4.7±0.1
Symbol	F	W	G	Н	L	ı
Dimension	31.5±0.2-0	36±0-0.2	19±0.35	7±0.35	110±0.7	5±0.35



#### Packaging Quantity

r donaging waariity							
Size	Quantity						
Size	Paper Tape Taping	Embossed Taping	Normal Bulk				
0402	10000		10000				
0603	4000		4000				
0805	4000	2000 / 3000	4000				
1206	4000	2000 / 3000	4000				
1210		2000 / 3000					
1812		1000					
2225							
3035							





## NPO(COG) DIELECTRIC CHARACTERISTIC INDUCTION & TEST METHOD

Item		Specification			Test Method		
Operating Temperature Range		-55°C ~ 125°C					
Appearance	<ol> <li>The chips h smooth.</li> <li>No exposed</li> <li>The outer e damages of</li> <li>No outer ele</li> </ol>	nic body color continuity ave no visual damages and must be very d inner-electrode, cracks or holes electrode should have no cracks, holes r surface oxidation ectrode prolongation or the prolongation half of that of the termination width.	Check by using microscope ≥10X				
Dimensions	With	nin the specified dimensions		Usiı	ng micrometer or verni	er calipers	
Capacitance	Wi	thin the specified tolerance	1.	Measuring	Temperature: 25°C±5	°C, Humidity: 30	% ~
Dissipation Factor (DF)	≤0.15%			Measuring C<1000pF	Voltage: 1.0±0.2V Frequency: , 1.0±0.1MHz, , 1.0±0.1KHz		
Insulation Resistance Withstanding Voltage	≥5x10 <sup>10</sup> Ω >3Ur			Must measure at rated voltage and measure the IR within 60±5s  Must measure at 3 times rated voltage, dwell time: 60±1s, no short and the changing/discharging current less than 50mA			
Capacitance Temperature Characteristic	Must meet the capacitor character temperature coefficient requirements within the operating temperature range			24±2hrs at rolle Measure the apacitance	60±5min at 150+0/-10 com temperature capacitance at -55~12 change ration compare specified range.	25°C or -55~85°(	C, the
Solderability	Tin coverage should be 95% of the outer electrode		Dip the capacitor into ethanol or colophony solution, and then dip it into 235±5°C eutectic solder solution for 2±0.5s. Dipping speed: 25±2.5mm/s				
	Appearance No defects visible		<ol> <li>Pre-heat for 60±5min at 150+0/-10°C, then set it for 24±2hrs at room temperature</li> <li>Pre-heat the capacitor according to the chart below. Dip the capacitor into 260±5°C eutectic solder solution for 10± 1s. Then set it for 24±2hrs at room temperature, then measure.</li> </ol>				
Resistance to	Capacitance Change Ratio ≤±2.5% or ±0.25pF (whichever larger)						for 10±
Soldering	D.F. Max 0.15%		Dippir	ng speed: 2		_	
				Stage	Temperature	Timer	
	I.R.	More than $50000M\Omega$		1	100°C ~ 120°C	1 min.	
				2	170°C ~ 200°C	1 min.	





Item		Specification	Test method			
Adhesive Strength of Termination	No removal of the	terminations or other defect shall occur	Capacitors mounted on a substrate, a force of 5N applied perpendicular to the plane of the substrate and parallel to the line joining the center of the terminations for 10±1s			
	Appearance	No defects or abnormities	Solder the capacitor to the test jig (glass epoxy resin board).  The capacitor should be subjected to a simple harmonic motion			
Vibration Resistance	Capacitance Within the specified tolerance range		having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz, shal			
	D.F.	Max 0.15%	be traversed in approximately 1min. This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (a total of 6 hours).			
Bending Resistance	No removal of termination, crack or visible damage.		Capacitors mounted on a substrate. The board shall then be bent by 1mm at a rate of 1mm/sec with 10N force			
			1. Heat the capacitor for 60±5min at 150+0/10°C, and then			

- Temperature

  Cycle

  No damage or abnormities visible
- StageTemperature(°C)Time(min.)1Lowest operating temperature ±330±32Normal Temperature2~33High operating temperature ±230±3

Normal temperature

Perform five cycles according to the four heat treatments listed below. Set it for 24±2hrs at room temperature, then

set it for 24 2hrs at room temperature.

measure.

	Appearance	No defects or abnormities
Humidity Steady State &	Capacitance Change Ratio	≤±5% or ±0.5pF (whichever larger)
Laod	D.F.	Max 0.15%
	I.R.	More than $10000M\Omega$
	Appearance	No defects or abnormities
Life Test	Capacitance Change Ratio	≤±5% or ±0.5pF (whichever larger)
	D.F.	Max 0.15%
	I.R.	More than $10000M\Omega$

Set the capacitor for 500+24/-0 hours at the condition of 40±2°C and 90-95% humidity. Then remove and set it for 24±2 hours at room temperature, then measure.

Load: Apply rated voltage to the capacitor for 500+24/-0 hours at the condition of 40±2°C and 90-95% humidity. Remove and set it for 24±2 hours at room temperature, then measure.

- Apply two times the rated voltage to the capacitor for 1000±12 hours at the upper temperature limits, the charging current should be less than 50mA.
- Remove and set it for 24±2 hours at room temperature, then measure.



2~3